

7N40

UTC UNISONIC TECHNOLOGIES CO., LTD

Preliminary

Power MOSFET

7A, 400V N-CHANNEL **POWER MOSFET**

DESCRIPTION

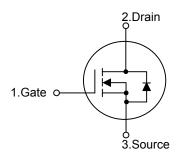
The UTC 7N40 is an N-channel mode power MOSFET using UTC's advanced technology to provide customers with planar stripe and DMOS technology. This technology specializes in allowing a minimum on-state resistance and superior switching performance. It also can withstand high energy pulse in the avalanche and commutation mode.

The UTC 7N40 is universally applied in electronic lamp ballast based on half bridge topology and high efficient switched mode power supply.



- * High switching speed
- * R_{DS(ON)}=0.9Ω @ V_{GS}=10V
- * 100% avalanche tested

SYMBOL

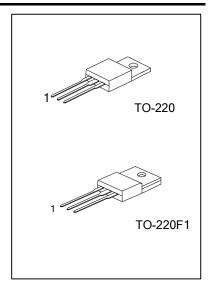


ORDERING INFORMATION

Ordering Number		Deekege	Pin Assignment			Dooking
Lead Free	Halogen Free	Package	1	2	3	Packing
7N40L-TA3-T	7N40G-TA3-T	TO-220	G	D	S	Tube
7N40L-TF1-T	7N40G-TF1-T	TO-220F1	G	D	S	Tube

Note: Pin Assignment: G: Gate D: Drain S: Source

7N40L-TA3-T (1)Packing Type (2)Package Type	(1) T: Tube (2) TA3: TO-220, TF1: TO-220F1
(3)Lead Free	(3) G: Halogen Free, L: Lead Free



■ ABSOLUTE MAXIMUM RATINGS (Tc=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V _{DSS}	400	V
Gate-Source Voltage		V _{GSS}	±30	V
Drain Current	Continuous (T _C =25°C)	I _D	7	А
	Pulsed (Note 2)	I _{DM}	28	Α
Avalanche Current (Note 2)		I _{AR}	7.0	А
Avalanche Energy	Single Pulsed (Note 3)	E _{AS}	360	mJ
	Repetitive (Note 2)	E _{AR}	9.8	mJ
Peak Diode Recovery dv/dt (Note 4)		dv/dt	4.5	V/ns
TO-220			98	W
Power Dissipation	TO-220F1		39	W
Derete chave 25°C		PD	0.78	W/°C
Derate above 25°C	TO-220F1		0.315	W/°C
Junction Temperature		TJ	+150	°C
Storage Temperature		T _{STG}	-55~+150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Repetitive Rating: Pulse width limited by maximum junction temperature

3. L = 13mH, I_{AS} = 7A, V_{DD} = 50V, R_G = 25 Ω , Starting T_J = 25°C

4. $I_{SD} \le 7A$, di/dt $\le 200A/\mu s$, $V_{DD} \le BV_{DSS}$, Starting $T_J = 25^{\circ}C$

■ THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Ambient		θ _{JA}	62.5	°C/W
Junction to Case	TO-220	0	1.28	°C/W
	TO-220F1	$\theta_{\rm JC}$	3.2	C/W



■ ELECTRICAL CHARACTERISTICS (T_c=25°C, unless otherwise specified)

SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
BV _{DSS}	I _D =250μA, V _{GS} =0V	400			V
nt ∆BV _{DSS} /∆T _J	Reference to 25°C, I _D =250µA		0.43		V/°C
I _{DSS}	V _{DS} =400V, V _{GS} =0V			1	μA
	V _{GS} =+30V, V _{DS} =0V			+100	nA
IGSS	V _{GS} =-30V, V _{DS} =0V			-100	nA
V _{GS(TH)}	V _{DS} =V _{GS} , I _D =250µA	2.0		4.0	V
R _{DS(ON)}	V _{GS} =10V, I _D =3.5A		0.75	0.9	Ω
C _{ISS}			600	780	pF
C _{oss}	V _{GS} =0V, V _{DS} =25V, f=1.0MHz		105	135	рF
			13	17	рF
					-
Q_{G}	1/(-10)/(1/-220)/(1-7)		16.5	22	nC
Q_{GS}			4.5		nC
Q_{GD}			8.5		nC
t _{D(ON)}			20	50	ns
t _R	V_{DD} =200V, I_D =7A, R_G =25 Ω		75	160	ns
t _{D(OFF)}	(Note 1, 2)		35	80	ns
t⊧			50	110	ns
CHARACTERIS	TICS				
ls				7	Α
I _{SM}				28	Α
V _{SD}	I _S =7A, V _{GS} =0V			1.5	V
t _{rr}	I _S =7A, V _{GS} =0V,		220		ns
Q _{RR}	dl _F /dt=100A/µs (Note 1)		1.3		μC
	BV_{DSS} nt $\triangle BV_{DSS} / \triangle T_J$ I_{DSS} I_{GSS} I_{GSS} $V_{GS(TH)}$ $R_{DS(ON)}$ C_{ISS} C_{RSS} C_{RSS} C_{RSS} Q_G Q_{GD} $t_{D(ON)}$ t_R $t_{D(OFF)}$ t_F CHARACTERIS I_S I_{SM} V_{SD} t_{rr}	$\begin{array}{ c c c c c c } & BV_{DSS} & I_{D} = 250 \mu A, V_{GS} = 0V \\ \hline nt & \triangle BV_{DSS} / \triangle T_J & Reference to 25^{\circ}C, I_{D} = 250 \mu A \\ \hline I_{DSS} & V_{DS} = 400V, V_{GS} = 0V \\ \hline I_{GSS} & \frac{V_{GS} = + 30V, V_{DS} = 0V}{V_{GS} = - 30V, V_{DS} = 0V} \\ \hline & V_{GS(TH)} & V_{DS} = V_{GS}, I_{D} = 250 \mu A \\ \hline & R_{DS(ON)} & V_{GS} = 10V, I_{D} = 3.5A \\ \hline & C_{ISS} & \\ \hline & C_{RSS} & \\ \hline & C_{RSS} & \\ \hline & Q_{G} & \\ V_{GS} = 0V, V_{DS} = 25V, f = 1.0 MHz \\ \hline & C_{RSS} & \\ \hline & V_{GS} = 10V, V_{DS} = 320V, I_{D} = 7A \\ \hline & Q_{GD} & \\ \hline & V_{DD} = 200V, I_{D} = 7A, R_{G} = 25\Omega \\ \hline & t_{D(ON)} & \\ \hline & t_{R} & V_{DD} = 200V, I_{D} = 7A, R_{G} = 25\Omega \\ \hline & t_{D(OFF)} & \\ \hline & t_{F} & \\ \hline \\$	$\begin{array}{ c c c c c c } & BV_{DSS} & I_{D}=250\mu A, V_{GS}=0V & 400 \\ \hline \mbox{Mt} & \begin{tabular}{lllllllllllllllllllllllllllllllllll$	$\begin{array}{ c c c c c c c c c c c c c c c c c c c$	$\begin{array}{c c c c c c c c c c c c c c c c c c c $

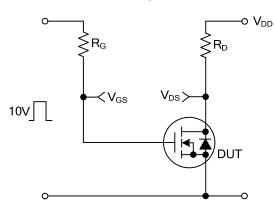
Notes: 1. Pulse Test: Pulse width \leq 300µs, Duty cycle \leq 2%

2. Essentially independent of operating temperature

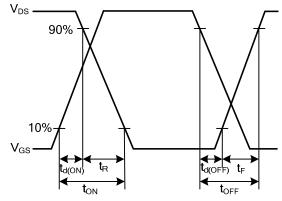


■ TEST CIRCUITS AND WAVEFORMS

Resistive Switching Test Circuit



Resistive Switching Waveforms



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